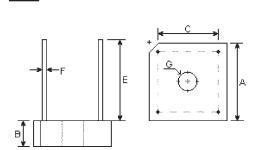


# BR605 THRU BR610

### SINGLE-PHASE SILICON BRIDGE Reverse Voltage - 50 to 1000 Volts Forward Current - 6.0 Amperes

#### Features

- Surge overload rating 125 amperes peak
- Low forward voltage drop
- Small size; simple installation
- Silver plated copper leads
- Mounting position: Any



BR6

DIMENSIONS									
DIM	inches		m	Note					
	Min.	Max.	Min.	Max.	inote				
А	0.580	0.620	14.69	15.71					
В	0.230	0.270	5.84	6.86					
С	0.405	0.445	10.29	11.31					
E	0.750	-	19.1	-					
F	0.038	0.042	0.97	1.07	ф				
G	Н								

# **Maximum Ratings and Electrical Characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

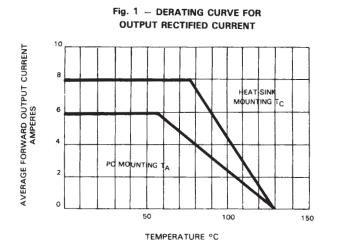
	Symbols	BR605	BR61	BR62	BR64	BR66	BR68	BR610	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS bridge input voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
$\begin{array}{llllllllllllllllllllllllllllllllllll$	I <sub>(AV)</sub>	6.0 6.0						Amps	
Peak forward surge current, 8.3mS single half sine-wave superimposed on rated load	I <sub>fsm</sub>	125.0							Amps
Maximum forward Voltage drop per element at 3.0A peak	V <sub>F</sub>	1.0							Volt
$\begin{array}{ll} \mbox{Maximum DC reverse current at rated} & T_{A} \mbox{=} 25^{\circ}\mbox{C} \\ \mbox{DC blocking voltage per element} & T_{A} \mbox{=} 100^{\circ}\mbox{C} \end{array}$	I <sub>R</sub>	10.0 1.0							uA mA
Operating temperature range	T	-55 to +125						°C	
Storage temperature range	T <sub>stg</sub>	-55 to +150						°C	

Notes:

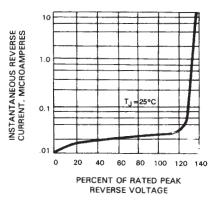
\* Unit mounted on metal chassis

\*\* Unit mounted on P.C. board

## **RATINGS AND CHARACTERISTIC CURVES**



#### Fig. 2 - TYPICAL REVERSE CHARACTERISTICS



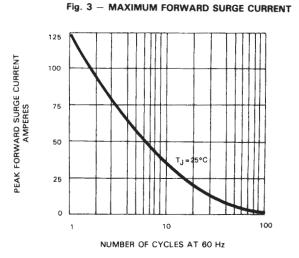
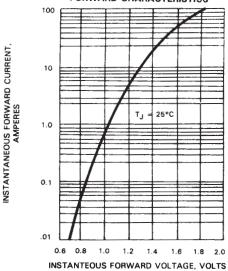


Fig. 4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



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